OSRAM BPX 65 Datasheet

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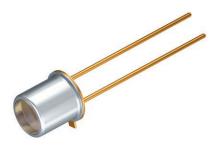




Metal Can TO18

BPX 65

Silicon PIN Photodiode





Applications

- Factory Automation

Features

- Package: hermetically sealed
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)
- Wavelength range ($S_{10\%}$) 350 nm to 1100 nm
- Short switching time (typ. 12 ns)
- Hermetically sealed metal can package (TO-18), suitable up to 125 °C

BPX 65 DATASHEET



Ordering Information

Туре	Photocurrent ¹⁾	Photocurrent typ.	Ordering Code
	$E_v = 1000 \text{ lx}; \text{ Std. Light A}; V_R = 5 \text{ V}$	E_v = 1000 lx; Std. Light A; V _R = 5 V I _P	
BPX 65	≥ 6.0 µA	10 µA	Q62702P0027



Maximum Ratings

T _A = 25 °C			
Parameter	Symbol		Values
Operating Temperature	T _{op}	min.	-40 °C
		max.	125 °C
Storage temperature	T _{stg}	min.	-40 °C
	o.g	max.	125 °C
Reverse voltage	V _R	max.	20 V
Reverse voltage	V _R	max.	50 V
$t \le 2 min; T_A = 25 °C$			
Total power dissipation	P _{tot}	max.	250 mW
ESD withstand voltage	V_{ESD}	max.	2 kV
acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	200		



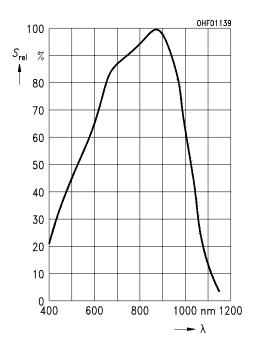
Characteristics

T _A = 25 °C			
Parameter	Symbol		Values
Spectral sensitivity $V_R = 5 V$	S	min. typ.	5.5 nA/lx 10 nA/lx
Wavelength of max sensitivity	$\lambda_{_{S max}}$	typ.	850 nm
Spectral range of sensitivity	$\lambda_{10\%}$	typ.	350 1100 nm
Radiant sensitive area	А	typ.	1.00 mm ²
Dimensions of active chip area	LxW	typ.	1 x 1 mm x mm
Half angle	φ	typ.	40 °
Dark current V _R = 20 V	۱ _R	typ. max.	1 nA 5 nA
Spectral sensitivity of the chip $\lambda = 850 \text{ nm}$	S_{λ}	typ.	0.55 A / W
Quantum yield of the chip	η	typ.	0.80 Electrons / Photon
Open-circuit voltage E _v = 1000 lx; Std. Light A; V _R = 0 V	V _o	min. typ.	270 mV 320 mV
Short-circuit current $E_v = 1000 \text{ Ix}$; Std. Light A; $V_R = 0 \text{ V}$	Ι _{sc}	typ.	10 µA
Rise time $V_R = 5 \text{ V}; \text{ R}_L = 50 \Omega; \lambda = 850 \text{ nm}$	t _r	typ.	0.012 µs
Fall time $V_R = 5 \text{ V}; \text{ R}_L = 50 \Omega; \lambda = 850 \text{ nm}$	t _r	typ.	0.012 µs
Forward voltage I _F = 100 mA; E = 0	V _F	typ.	1.3 V
Capacitance V _R = 0 V; f = 1 MHz; E = 0	C ₀	typ.	11 pF
Temperature coefficient of voltage	TC _v	typ.	-2.6 mV / K
Temperature coefficient of short-circuit current Std. Light A	TC	typ.	0.18 % / K
Noise equivalent power $V_R = 20 V; \lambda = 850 \text{ nm}$	NEP	typ.	0.033 pW / Hz ^{1/2}
Detection limit $V_R = 20 \text{ V}; \lambda = 850 \text{ nm}$	D*	typ.	3.1e12 cm x Hz ^{1/2} / W



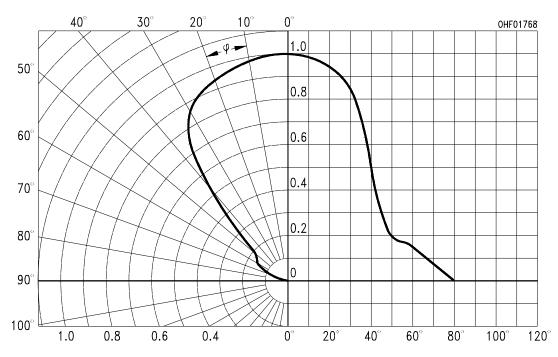
Relative Spectral Sensitivity ^{2), 3)}

 $S_{rel} = f(\lambda)$



Directional Characteristics ^{2), 3)}

 $S_{rel} = f(\phi)$

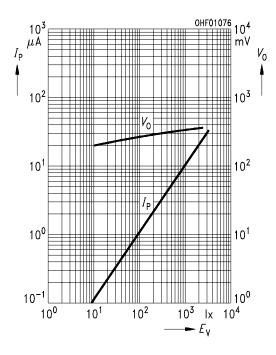


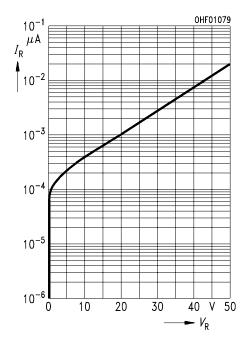


Photocurrent/Open-Circuit Voltage ^{2), 3)} Dark Current ^{2), 3)}

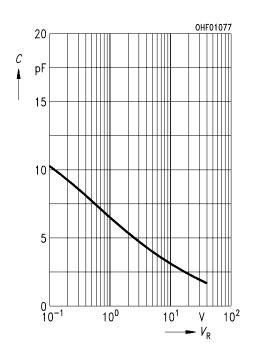
³⁾ **Dark Current** $I_R = f(V_R); E = 0$

 $I_{_{P}} (V_{_{R}} = 5 \text{ V}) / V_{_{O}} = f (E_{_{v}})$





Capacitance ^{2), 3)} C = f (V_R); f = 1MHz; E = 0; T_A = 25°C

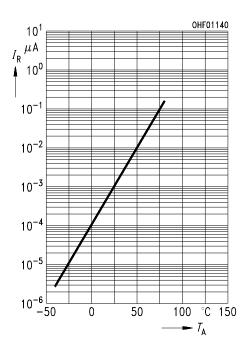






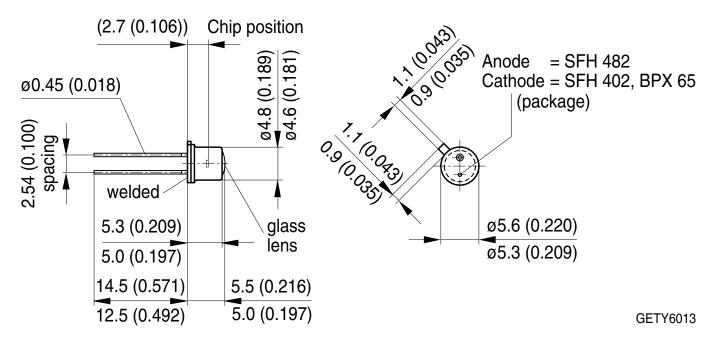
Dark Current ²⁾

 $I_{_{R}} = f(T_{_{A}}); E = 0; V_{_{R}} = 5 V$





Dimensional Drawing ⁴⁾



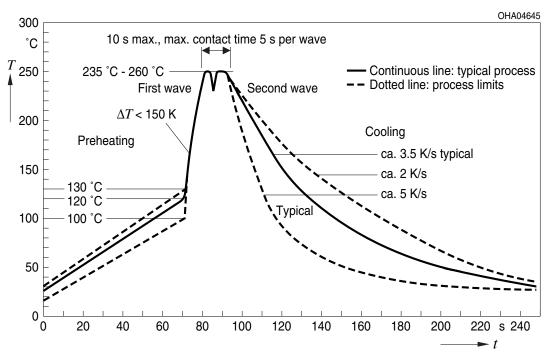
Further Information:

Approximate Weight:	332.0 mg
Package marking:	Anode



TTW Soldering

IEC-61760-1 TTW



Notes

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



Glossary

- ¹⁾ **Photocurrent:** The photocurrent values are measured (by irradiating the devices with a homogenous light source and applying a voltage to the device) with a tolerance of ±11 %.
- ²⁾ Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ³⁾ **Testing temperature:** TA = 25°C (unless otherwise specified)
- ⁴⁾ **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.



Revision History

Version	Date	Change
1.4	2023-01-24	Brand New Layout Applications



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